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- EPIC™ (Enhanced-Performance Implanted CMOS) Process
- Inputs Are TTL-Voltage Compatible
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Package Options Include Plastic Small-Outline Transistor (DBV, DCK) Packages

DBV OR DCK PACKAGE (TOP VIEW) A 1 5 VCC B 2 GND 3 4 Y

description

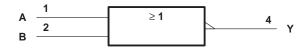
This device contains a single 2-input NOR gate that performs the Boolean function $Y = \overline{A} \bullet \overline{B}$ or $Y = \overline{A + B}$ in positive logic.

The SN74AHCT1G02 is characterized for operation from -40°C to 85°C.

FUNCTION TABLE (each gate)

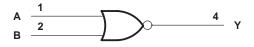
INP	JTS	OUTPUT
Α	В	Υ
Н	Χ	L
Х	Н	L
L	L	Н

logic symbol†



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)





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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage range, V _{CC}	–0.5 V to 7 V
Input voltage range, V _I (see Note 1)	–0.5 V to 7 V
Output voltage range, VO (see Note 1)	
Input clamp current, I _{IK} (V _I < 0)	–20 mA
Output clamp current, I _{OK} (V _O < 0 or V _O > V _{CC})	±20 mA
Continuous output current, I_O ($V_O = 0$ to V_{CC})	±25 mA
Continuous current through V _{CC} or GND	±50 mA
Package thermal impedance, θ_{JA} (see Note 2): DBV package	347°C/W
DCK package	389°C/W
Storage temperature range, T _{stg}	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions (see Note 3)

		MIN	MAX	UNIT
VCC	Supply voltage	4.5	5.5	V
VIH	High-level input voltage	2		V
V _{IL}	Low-level input voltage		0.8	V
٧ _I	Input voltage	0	5.5	V
VO	Output voltage	0	VCC	V
IOH	High-level output current		-8	mA
l _{OL}	Low-level output current		8	mA
Δt/Δν	Input transition rise or fall rate		20	ns/V
TA	Operating free-air temperature	-40	85	°C

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	vcc	T _A = 25°C			MIN	MAX	UNIT
	TEST CONDITIONS		MIN	TYP	MAX	INIIN	WAX	UNII
Vou	I _{OH} = -50 μA	4.5 V	4.4	4.5		4.4		V
VOH	I _{OH} = -8 mA		3.94			3.8		
VOL	I _{OL} = 50 μA	4.5 V			0.1		0.1	٧
	$I_{OL} = 8 \text{ mA}$	4.5 V			0.36		0.44	
lį	$V_I = V_{CC}$ or GND	0 V to 5.5 V			±0.1		±1	μΑ
ICC	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			1		10	μΑ
Δl _{CC} ‡	One input at 3.4 V, Other inputs at GND or V _{CC}	5.5 V			1.35		1.5	mA
C _i	$V_I = V_{CC}$ or GND	5 V		4	10		10	pF

[‡]This is the increase in supply current for each input at one of the specified TTL voltage levels rather than 0 V or V_{CC}.



NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

^{2.} The package thermal impedance is calculated in accordance with JESD 51.

SN74AHCT1G02 SINGLE 2-INPUT POSITIVE-NOR GATE

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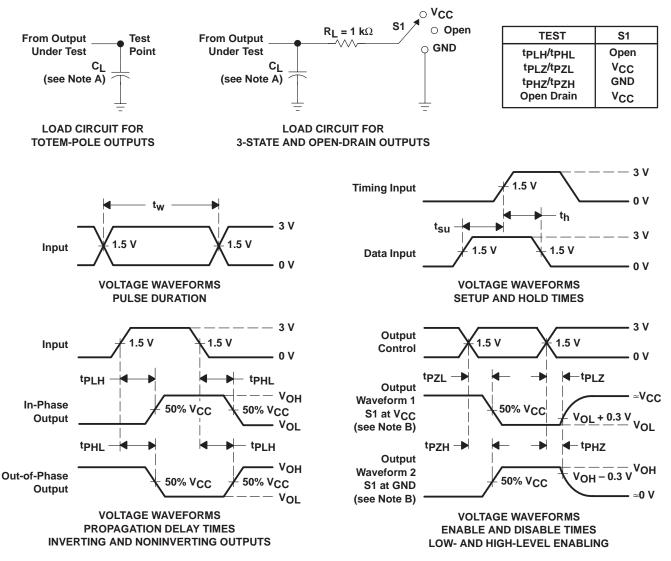
switching characteristics over recommended operating free-air temperature range, $V_{CC}=5~V\pm0.5~V$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM TO (OUTPUT)	то	LOAD	T _A = 25°C			MIN	MAX	UNIT
		CAPACITANCE	MIN	TYP	MAX	IVIIIV	WAX	UNIT	
^t PLH	A or B	Y	V C. 45 p.F		2.4	5.5	1	6.5	no
t _{PHL}	AUID		C _L = 15 pF		3.5	5.5	1	6.5	ns
t _{PLH}	A or B	Y	C _L = 50 pF		3.4	7.5	1	8.5	no
t _{PHL}					4.5	7.5	1	8.5	ns

operating characteristics, V_{CC} = 5 V, T_A = 25°C

PARAMETER		TEST C	ONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance	No load,	f = 1 MHz	17	pF

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_I includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, $t_\Gamma \leq 3$ ns, $t_f \leq 3$ ns.
- D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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